

# MURB1610CT / MURB1620CT

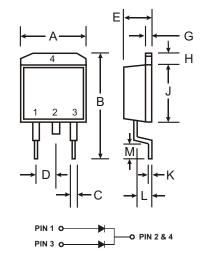
### **16A SURFACE MOUNT SUPER-FAST RECTIFIER**

#### **Features**

- Glass Passivated Die Construction
- Diffused Junction
- Super-Fast Recovery Times for High Efficiency
- High Current Capability and Low Forward Voltage Drop
- Surge Overload Rating to 100A Peak
- Low Reverse Leakage Current
- Also Available in Lead Free Version

### **Mechanical Data**

- Case: Molded Plastic
- Plastic Material: UL Flammability Classification Rating 94V-0
- Moisture sensitivity: Level 1 per J-STD-020A
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish). Please see Ordering Information, Note 5, on Page 3
- Polarity: See Diagram
- Weight: 1.7 grams (approx.)



D <sup>2</sup> PAK					
Dim	Min	Max			
Α	9.65	10.69			
В	14.60	15.88			
С	0.51	1.14			
D	2.29	2.79			
E	4.37	4.83			
G	1.14	1.40			
Н	1.14	1.40			
J	8.25	9.25			
K	0.30	0.64			
L	2.03	2.92			
M	2.29	2.79			
All Dimensions in mm					

### Maximum Ratings and Electrical Characteristics @ TA = 25°C unless otherwise specified

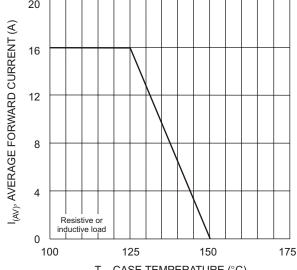
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic		Symbol	MURB1610CT	MURB1620CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage		V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	100	200	V
RMS Reverse Voltage		V <sub>R(RMS)</sub>	70	140	V
Average Rectified Output Current	@ T <sub>C</sub> = 125°C	lo	16		Α
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)		I <sub>FSM</sub>	100		А
Forward Voltage	@ I <sub>F</sub> = 8.0A	V <sub>FM</sub>	0.975		V
Peak Reverse Current at Rated DC Blocking Voltage	@ T <sub>A</sub> = 25°C @ T <sub>A</sub> = 150°C	I <sub>RM</sub>	5.0 250		μА
Maximum Recovery Time (Note 2)		t <sub>rr</sub>	3	0	ns
Typical Total Capacitance (Note 3)		Ст	8	5	pF
Typical Thermal Resistance Junction to Case		$R_{\theta JC}$	1.	.5	°C/W
Operating and Storage Temperature Range		T <sub>j</sub> , T <sub>STG</sub>	-65 to	+150	°C

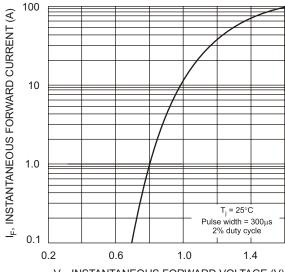
Notes: 1. Unit mounted on PC board with 5.0 mm<sup>2</sup> (0.013 mm thick) copper pad as heat sink.

- 2. Measured with  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{rr} = 0.25A$ .
- 3. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V DC.

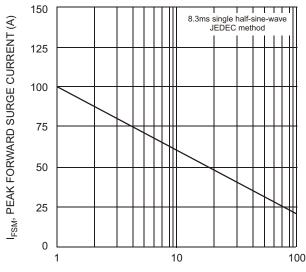




T<sub>C</sub>, CASE TEMPERATURE (°C) Fig. 1 Forward Current Derating Curve



 $\rm V_{\rm F}$ , INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics per Element



NUMBER OF CYCLES AT 60Hz Fig. 3 Max Non-Repetitive Surge Current

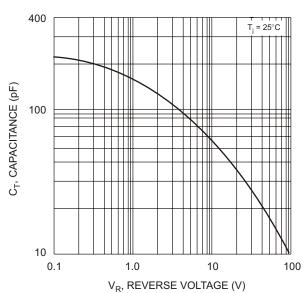
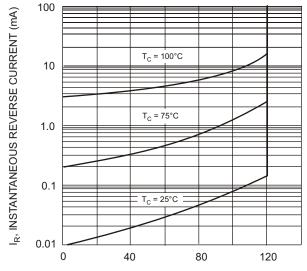


Fig. 4 Typical Total Capacitance per Element



PERCENT OF RATED PEAK REVERSE VOLTAGE (%) Fig. 5 Typical Reverse Characteristics

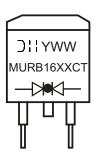


## **Ordering Information** (Note 4)

Device	Packaging	Shipping
MURB1610CT-13	D <sup>2</sup> PAK	800/Tape & Reel
MURB1620CT-13	D <sup>2</sup> PAK	800/Tape & Reel

Notes:

- For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.
  For Lead Free plating (matte tin), please add "-F" suffix to the part number. Example: MURB1610CT-13-F.



MURB16XXCT = Product type marking code OH = Manufacturers' code marking YWW = Date code marking Y = Last digit of year ex: 2 for 2002 WW = Week code 01 to 52